



M74HCT4053

TRIPLE 2-CHANNEL ANALOG MULTIPLEXER/DEMULTIPLEXER

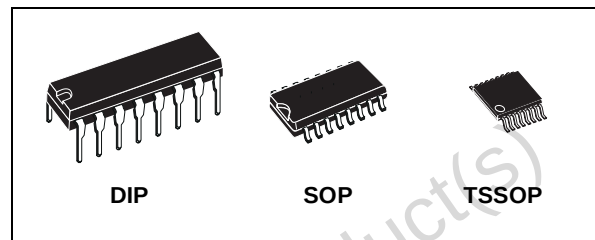
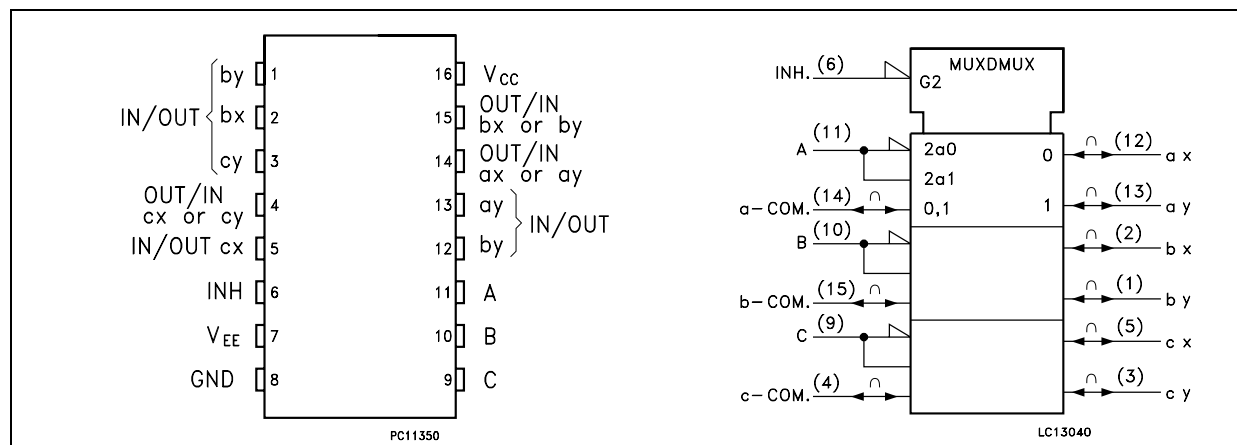
- LOW POWER DISSIPATION:
 $I_{CC} = 4\mu A$ (MAX.) at $T_A = 25^\circ C$
- LOGIC LEVEL TRANSLATION TO ENABLE
TTL LOGIC SIGNAL TO COMMUNICATE
WITH $\pm 5V$ ANALOG SIGNAL
- LOW "ON" RESISTANCE:
70 Ω TYP. ($V_{CC} - V_{EE} = 4.5V$)
50 Ω TYP. ($V_{CC} - V_{EE} = 9V$)
- WIDE ANALOG INPUT VOLTAGE RANGE:
 $\pm 6V$
- FAST SWITCHING:
 $t_{pd} = 13ns$ (TYP.) at $T_A = 25^\circ C$
- LOW CROSSTALK BETWEEN SWITCHES
- HIGH ON/OFF OUTPUT VOLTAGE RATIO
- WIDE OPERATING SUPPLY VOLTAGE
RANGE ($V_{CC} - V_{EE}$) = 2V TO 12V
- LOW SINE WAVE DISTORTION:
0.02% at $V_{CC} - V_{EE} = 9V$
- COMPATIBLE WITH TTL OUTPUTS:
 $V_{IH} = 2V$ (MIN.) $V_{IL} = 0.8V$ (MAX.)
- PIN AND FUNCTION COMPATIBLE WITH
74 SERIES 4053

DESCRIPTION

The M74HCT4053 is a triple two-channel analog MULTIPLEXER/DEMULTIPLEXER fabricated with silicon gate C²MOS technology and it is pin to pin compatible with the equivalent metal gate CMOS4000B series.

It contains 6 bidirectional and digitally controlled analog switches.

PIN CONNECTION AND IEC LOGIC SYMBOLS



ORDER CODES

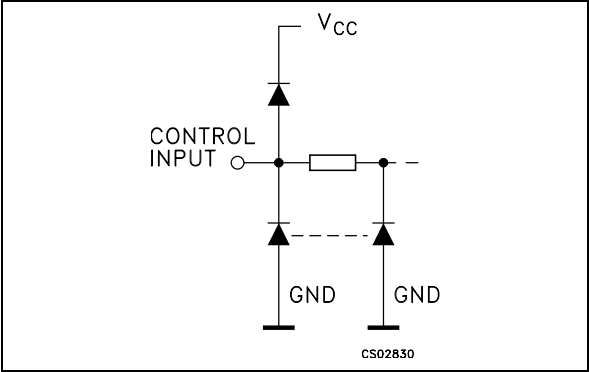
PACKAGE	TUBE	T & R
DIP	M74HCT4053B1R	
SOP	M74HCT4053M1R	M74HCT4053RM13TR
TSSOP		M74HCT4053TTR

A built-in level shifting is included to allow an input range up to $\pm 6V$ (peak) for an analog signal with digital control signal of 0 to 6V.

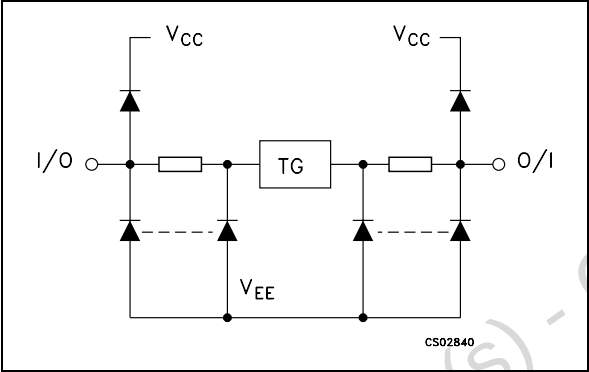
V_{EE} supply pin is provided for analog input signals. It has an inhibit (INH) input terminal to disable all the switches when high, compatible with TTL output level. For operation as a digital multiplexer/demultiplexer, V_{EE} is connected to GND. A, B and C control inputs select one of a pair of channels, they are compatible with TTL output level.

All inputs are equipped with protection circuits against static discharge and transient excess voltage.

CONTROL INPUT EQUIVALENT CIRCUIT



I/O EQUIVALENT CIRCUIT



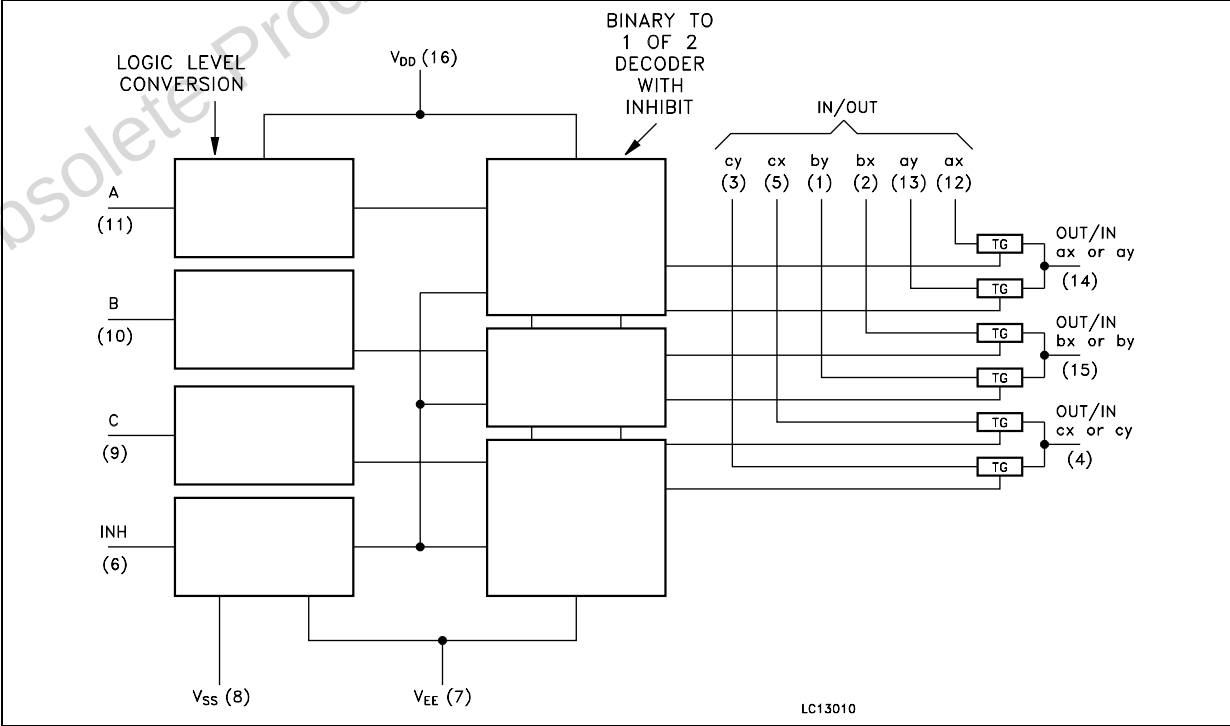
PIN DESCRIPTION

PIN No	SYMBOL	NAME AND FUNCTION
2, 1	bx, by	Independent Input Outputs
5, 3	cx, cy	Independent Input Outputs
6	INH	INHIBIT Input
7	V _{EE}	Negative Supply Voltage
11, 10, 9	A, B, C	Select Inputs
12, 13	ax, ay	Independent Input Outputs
14, 15, 4	ax to cy	Common Output/Input
8	GND	Ground (0V)
16	V _{CC}	Positive Supply Voltage

TRUTH TABLE

INPUT STATE		ON CHANNEL
INH	A or B or C	
L	L	ax or bx or cx
L	H	ay or by or cy
H	X	NONE

FUNCTIONAL DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage	-0.5 to +7	V
$V_{CC} - V_{EE}$	Supply Voltage	-0.5 to +13	V
V_I	Control Input Voltage	-0.5 to $V_{CC} + 0.5$	V
$V_{I/O}$	Switch I/O Voltage	$V_{EE} - 0.5$ to $V_{CC} + 0.5$	V
I_{CK}	Control Input Diode Current	± 20	mA
$I_{I/O}$	I/O Diode Current	± 20	mA
I_T	Switch Through Current	± 25	mA
I_{CC} or I_{GND}	DC V_{CC} or Ground Current	± 50	mA
P_D	Power Dissipation	500(*)	mW
T_{stg}	Storage Temperature	-65 to +150	°C
T_L	Lead Temperature (10 sec)	300	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied.

(*) 500mW at 65 °C; derate to 300mW by 10mW/°C from 65°C to 85°C

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage	4.5 to 5.5	V
V_{EE}	Supply Voltage	-6 to 0	V
$V_{CC} - V_{EE}$	Supply Voltage	2 to 12	V
V_I	Input Voltage	0 to V_{CC}	V
$V_{I/O}$	I/O Voltage	V_{EE} to V_{CC}	V
T_{op}	Operating Temperature	-55 to 125	°C
t_r, t_f	Input Rise and Fall Time	$V_{CC} = 4.5$ to $5.5V$ 0 to 500	ns

DC SPECIFICATIONS

Symbol	Parameter	Test Condition			Value						Unit	
		V _{CC} (V)	V _{EE} (V)		T _A = 25°C			-40 to 85°C		-55 to 125°C		
					Min.	Typ.	Max.	Min.	Max.	Min.		Max.
V _{IHC}	High Level Input Voltage	4.5 to 5.5			2.0			2.0		2.0		V
V _{ILC}	Low Level Input Voltage	4.5 to 5.5					0.8		0.8		0.8	V
R _{ON}	ON Resistance	4.5	GND	V _I = V _{IHC} or V _{ILC} V _{I/O} = V _{CC} to V _{EE} I _{I/O} ≤ 2mA		85	180		225		270	Ω
		4.5	-4.5		55	120		150		180		
		4.5	GND	V _I = V _{IHC} or V _{ILC} V _{I/O} = V _{CC} or V _{EE} I _{I/O} ≤ 2mA		70	150		190		230	
		4.5	-4.5		50	100		125		150		
ΔR _{ON}	Difference of ON Resistance between switches	4.5	GND	V _I = V _{IHC} or V _{ILC} V _{I/O} = V _{CC} or V _{EE} I _{I/O} ≤ 2mA		10	30		35		45	Ω
		4.5	-4.5		5	12		15		18		
I _{OFF}	Input/Output Leakage Current (SWITCH OFF)	5.5	GND	V _{OS} = V _{CC} or GND V _{IS} = GND or V _{CC} V _I = V _{ILC} or V _{IHC}			±0.06		± 0.6		± 1.0	μA
		5.5	-6.0			± 0.1		± 1		± 1		
I _{Iz}	Switch Input Leakage Current (SWITCH ON, OUTPUT OPEN)	5.5	GND	V _{OS} = V _{CC} or GND V _I = V _{IHC} or V _{ILC}			±0.06		± 0.6		± 1.0	μA
		5.5	-6.0			± 0.1		± 1		± 1		
I _I	Input Leakage Current	5.5	GND	V _I = V _{CC} or GND			± 0.1		± 0.1		± 1	μA
I _{CC}	Quiescent Supply Current	5.5	GND	V _I = V _{CC} or GND			4		40		80	μA
		5.5	-6.0			8		80		160		
ΔI _{CC}	Additional Quiescent Supply Current per input pin	4.5 to 5.5	GND	V _I = V _{CC} - 2.1V other input at V _{CC} or GND		100	360		450		490	μA

AC ELECTRICAL CHARACTERISTICS ($C_L = 50 \text{ pF}$, Input $t_r = t_f = 6 \text{ ns}$)

Symbol	Parameter	Test Condition			Value						Unit	
		V _{CC} (V)	V _{EE} (V)		T _A = 25°C			-40 to 85°C		-55 to 125°C		
					Min.	Typ.	Max.	Min.	Max.	Min.		Max.
Φ _{I/O}	Phase Difference Between Input and Output	4.5	GND	C _L = 50pF		5	12		15		18	ns
		4.5	-4.5			4	8		10		12	
t _{PZL} t _{PZH}	Output Enable Time	4.5	GND	R _L = 1KΩ		13	45		56		68	ns
		4.5	-4.5	C _L = 50pF		11	34		43		51	
t _{PLZ} t _{PHZ}	Output Disable Time	4.5	GND	R _L = 1KΩ		25	38		48		58	ns
		4.5	-4.5	C _L = 50pF		19	31		39		47	

CAPACITANCE CHARACTERISTICS

Symbol	Parameter	Test Condition			Value						Unit	
		V _{CC} (V)	V _{EE} (V)		T _A = 25°C			-40 to 85°C		-55 to 125°C		
					Min.	Typ.	Max.	Min.	Max.	Min.		Max.
C _{IN}	Input Capacitance	5.0				5	10		10		10	pF
C _{I/O}	Common Terminal Capacitance	5.0	-5.0			11	20		20		20	pF
C _{I/O}	Switch Terminal Capacitance	5.0	-5.0			7	15		15		15	pF
C _{IOS}	Feed Through Capacitance	5.0	-5.0			0.75	2		2		2	pF
C _{PD}	Power Dissipation Capacitance (note 1)	5.0	GND			67						pF

1) C_{PD} is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to Test Circuit). Average operating current can be obtained by the following equation. $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}$

ANALOG SWITCH CHARACTERISTICS (GND = 0V; T_A = 25°C)

Symbol	Parameter	Test Condition			Value	Unit
		V _{CC} (V)	V _{EE} (V)	V _{IN} (V _{p-p})	Typ.	
	Sine Wave Distortion	2.25	-2.25	4	0.025	%
		4.5	-4.5	8	0.020	
	Sine Wave Distortion	2.25	-2.25	4	0.12	%
		4.5	-4.5	8	0.06	
f _{MAX}	Frequency Response (Switch ON) (*)	2.25	-2.25	Adjust f _{IN} voltage to obtain 0 dBm at V _{OS} . Increase f _{IN} Frequency until dB meter reads -3dB R _L = 50Ω, C _L = 10 pF, f _{IN} = 1KHz sine wave	120	MHz
		4.5	-4.5		190	
f _{MAX}	Frequency Response (Switch ON) (**)	2.25	-2.25	Adjust f _{IN} voltage to obtain 0 dBm at V _{OS} . Increase f _{IN} Frequency until dB meter reads -3dB R _L = 50Ω, C _L = 10 pF, f _{IN} = 1KHz sine wave	95	MHz
		4.5	-4.5		150	
		6.0	-6.0			
	Feed through Attenuation (Switch OFF)	2.25	-2.25	V _{IN} is centered at (V _{CC} - V _{EE})/2 Adjust input for 0 dBm R _L = 600Ω, C _L = 50 pF, f _{IN} = 1MHz sine wave	-50	dB
		4.5	-4.5		-50	
	Crosstalk (Control Input to Signal Output)	4.5	0	Adjust R _L at set up so that I _S = 0A. R _L = 600Ω, C _L = 50 pF, f _{IN} = 1MHz square wave between V _{CC} and GND tr=tf= 6 ns	60	mV
		4.5	-4.5		140	
	Crosstalk (between any two switches)	2.25	-2.25	Adjust V _{IN} to obtain 0dBm at input R _L = 600Ω, C _L = 50 pF, f _{IN} = 1MHz sine wave	-50	dB
		4.5	-4.5		-50	

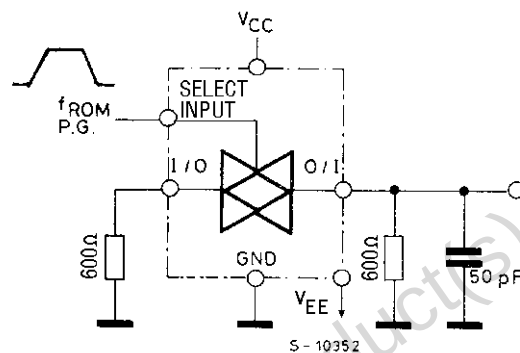
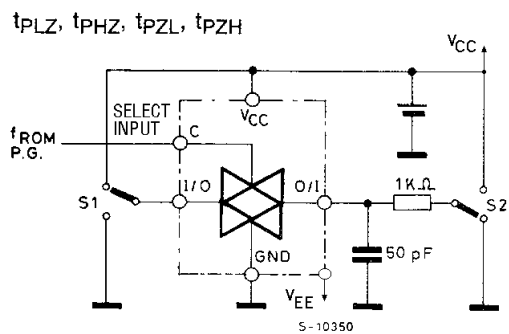
(*) Input COMMON Terminal, and measured at SWITCH Terminal

(**) Input SWITCH Terminal, and measured at common Terminal

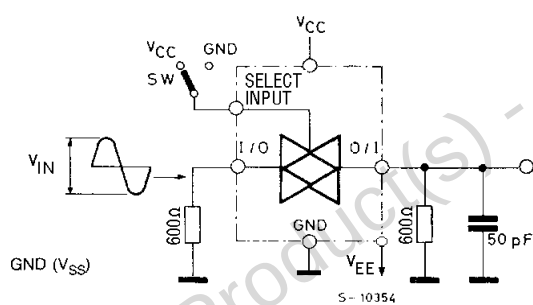
NOTE: These characteristics are determined by the design of the device.

SWITCHING CHARACTERISTICS TEST CIRCUIT

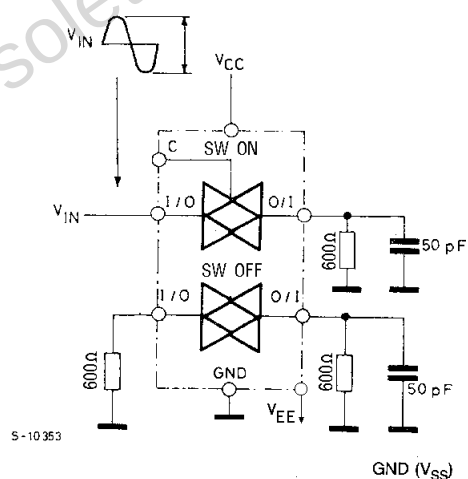
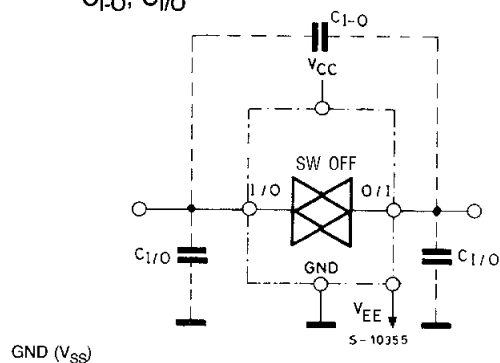
CROSSTALK (control to output)



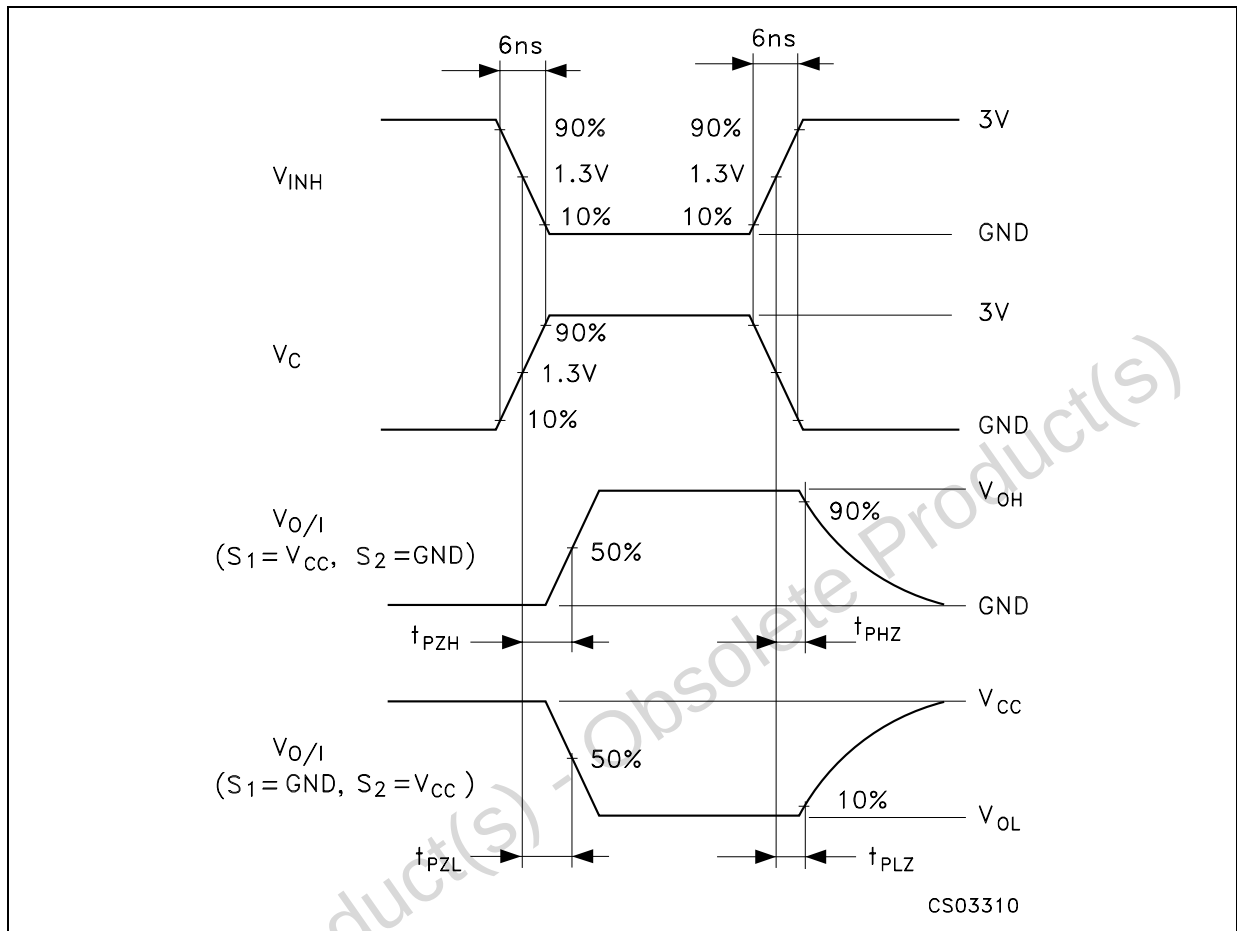
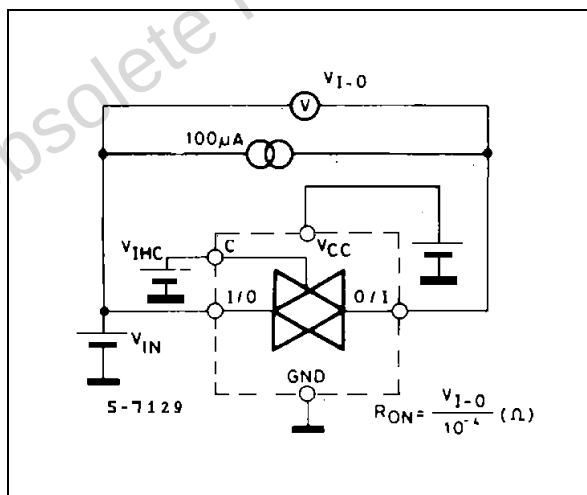
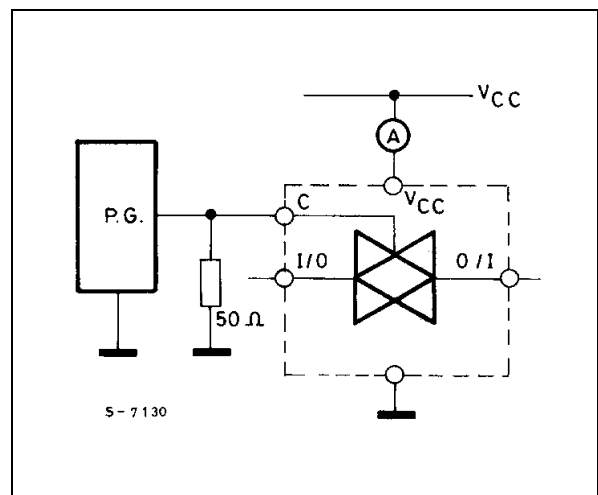
BANDWIDTH AND FEEDTHROUGH ATTENUATION



CROSSTALK BETWEEN ANY TWO SWITCHES

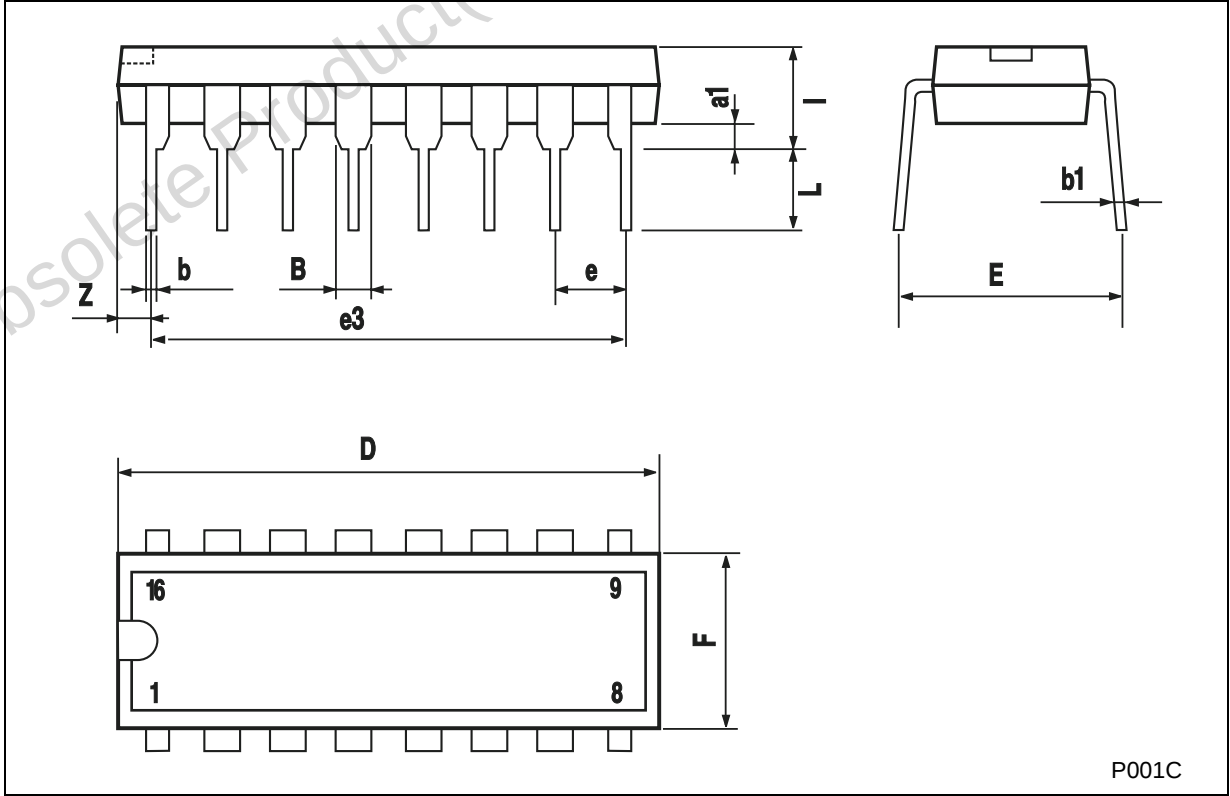
 C_{I-O} , $C_{I/O}$ 

SWITCHING CHARACTERISTICS WAVEFORM

CHANNEL RESISTANCE (R_{ON}) I_{CC} (Opr.)

Plastic DIP-16 (0.25) MECHANICAL DATA

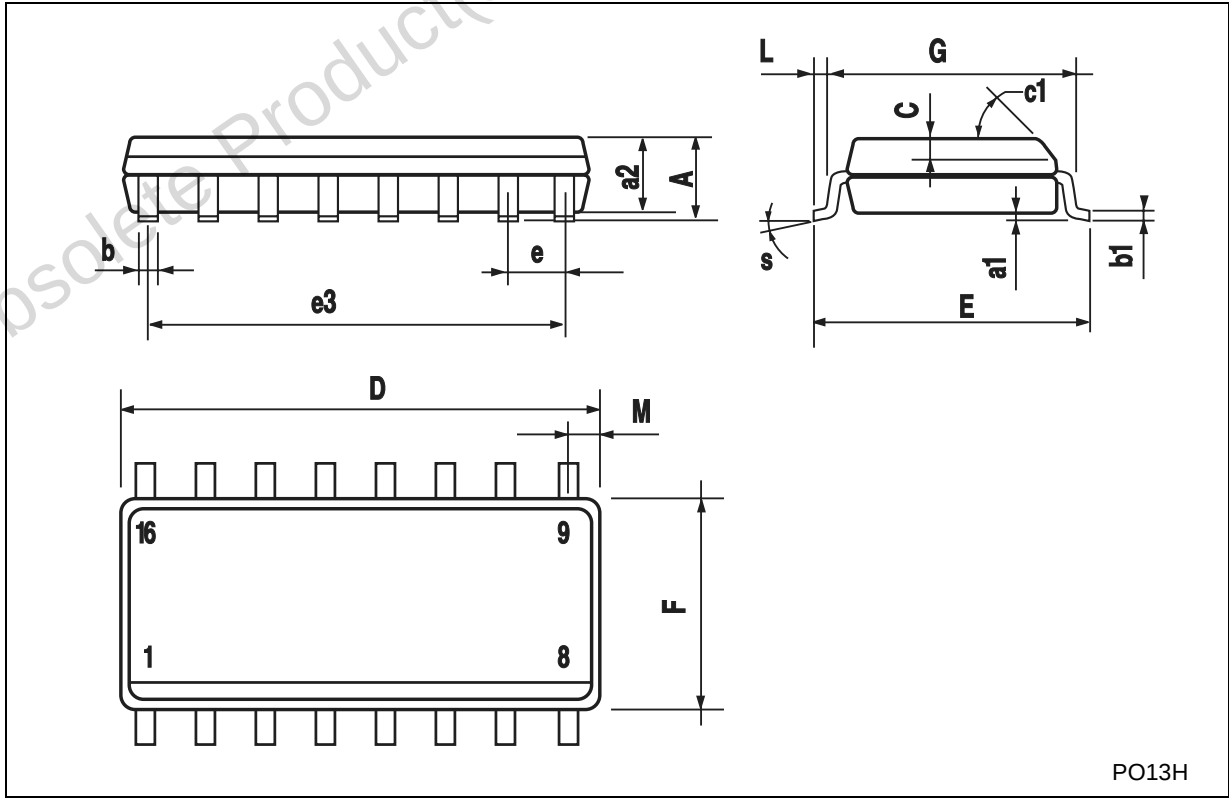
DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
a1	0.51			0.020		
B	0.77		1.65	0.030		0.065
b		0.5			0.020	
b1		0.25			0.010	
D			20			0.787
E		8.5			0.335	
e		2.54			0.100	
e3		17.78			0.700	
F			7.1			0.280
I			5.1			0.201
L		3.3			0.130	
Z			1.27			0.050



P001C

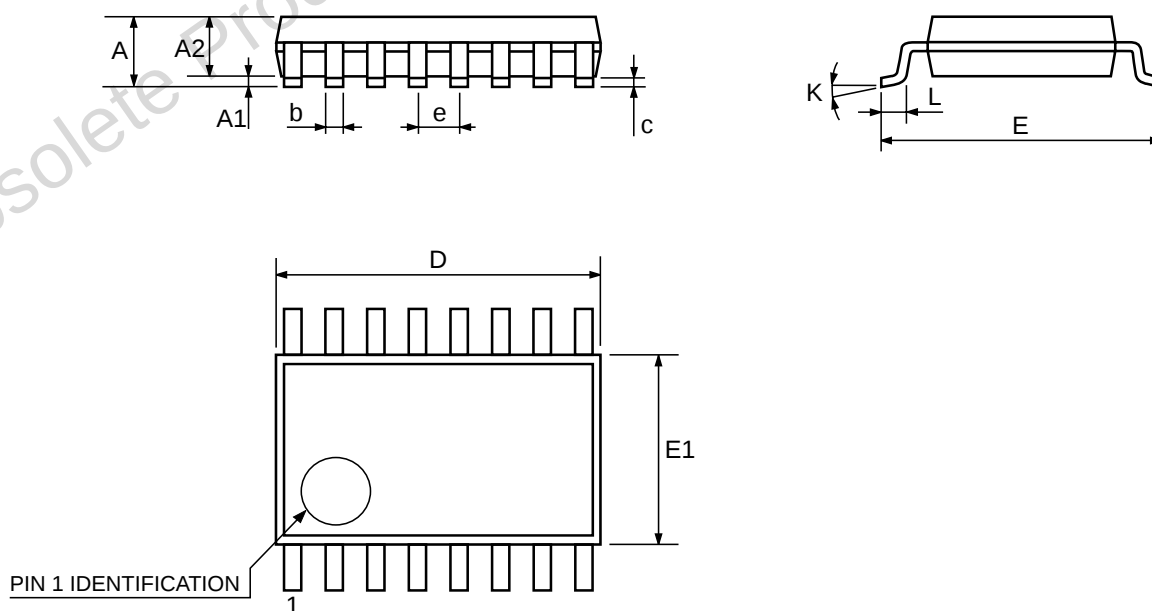
SO-16 MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A			1.75			0.068
a1	0.1		0.2	0.003		0.007
a2			1.65			0.064
b	0.35		0.46	0.013		0.018
b1	0.19		0.25	0.007		0.010
C		0.5			0.019	
c1	45° (typ.)					
D	9.8		10	0.385		0.393
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		8.89			0.350	
F	3.8		4.0	0.149		0.157
G	4.6		5.3	0.181		0.208
L	0.5		1.27	0.019		0.050
M			0.62			0.024
S	8° (max.)					



TSSOP16 MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A			1.2			0.047
A1	0.05		0.15	0.002	0.004	0.006
A2	0.8	1	1.05	0.031	0.039	0.041
b	0.19		0.30	0.007		0.012
c	0.09		0.20	0.004		0.0089
D	4.9	5	5.1	0.193	0.197	0.201
E	6.2	6.4	6.6	0.244	0.252	0.260
E1	4.3	4.4	4.48	0.169	0.173	0.176
e		0.65 BSC			0.0256 BSC	
K	0°		8°	0°		8°
L	0.45	0.60	0.75	0.018	0.024	0.030



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